## NSN 5961-00-470-2659

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View Online at https://aerobasegroup.com/nsn/5961-00-470-2659 **Inclosure Material:** Metal **Overall Length:** 0.710 inches Overall Diameter: 0.187 inches **Mounting Facility Quantity: Electrode Internally-electrically Connected To Case:** Anode **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.189 inches **Thread Size:** 0.112 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 12.0 regulator voltage **Voltage Tolerance In Percent:** -5.0/+5.0 **Current Rating Per Characteristic:** 200.00 milliamperes all primaries horsepower metric and 770.00 milliamperes repetitive peak forward current **Power Rating Per Characteristic:** 10.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius case **Test Data Document:** 49956-373433 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator:** Unc **Terminal Type And Quantity:** 1 threaded stud and 1 solder stud Shelf Life: N/a **Unit Of Measure:** 

No

Demilitarization:

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